

# PTVSHC1DF18VB ESD Protector

### Description

The PTVSHC1DF18VB ESD protector is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC1DF18VB protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PTVSHC2DF18VB is available in a SOD-123FL package with working voltages of 18 volt. It is used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge)



#### Feature

- 2200W Peak pulse power per line (t<sub>P</sub> = 8/20µs)
- SOD-123FL package
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
  ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 80A (5/50ns)

### **Applications**

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
  - MP3 players

### **Mechanical Characteristics**

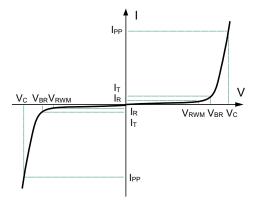
- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 2 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

# PTVSHC1DF18VB

# **ESD Protector**

### **Electronics Parameter**

Symbol	Parameter	
VRWM	Peak Reverse Working Voltage	
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>	
V <sub>BR</sub>	Breakdown Voltage @ I⊤	
Ιτ	Test Current	
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P <sub>PP</sub>	Peak Pulse Power	
CJ	Junction Capacitance	



# Electrical characteristics per line@25°C( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V <sub>RWM</sub>				18	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> =1mA	19.5	22	23.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =18V			1	μA
Clamping Voltage	Vc	I <sub>PP</sub> =75Α t <sub>P</sub> = 8/20μs		32	34	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz		185	200	pF

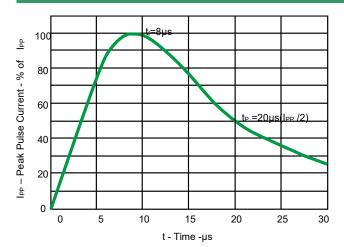
# Absolute maximum rating@25°C

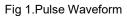
Rating	Symbol	Value	Units
Peak Pulse Power ( $t_P = 8/20\mu S$ )	P <sub>pp</sub>	2200	W
Lead Soldering Temperature	ΤL	260 (10 sec)	°C
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

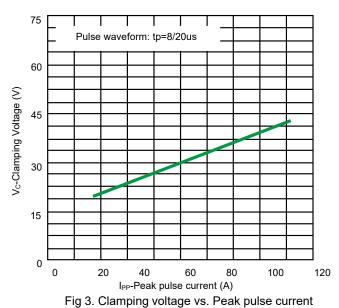
## **ESD** Protector

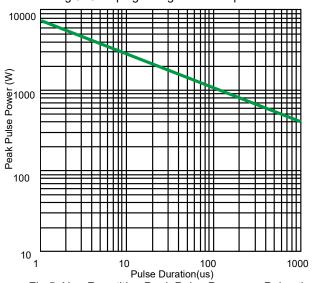
### PTVSHC1DF18VB

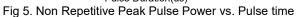
### **Typical Characteristics**











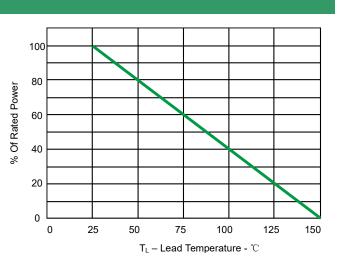
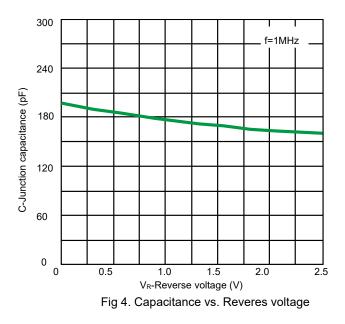


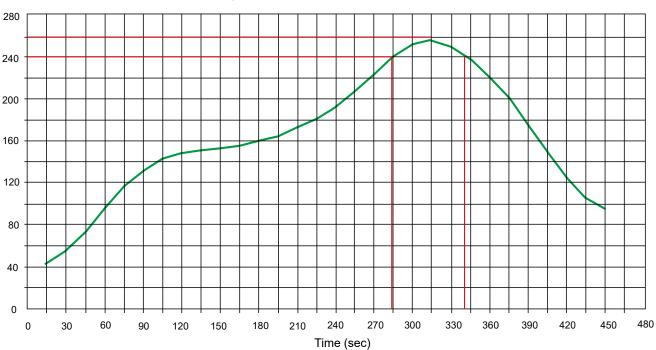
Fig 2.Power Derating Curve



## **ESD** Protector

### PTVSHC1DF18VB

#### **Solder Reflow Recommendation**



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

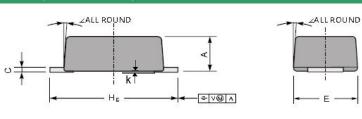
### **PCB** Design

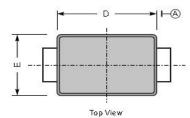
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

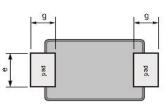
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

# **ESD Protector**

# Product dimension (SOD-123FL)



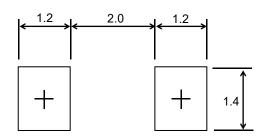




Bottom View

Unit:mm

Dim	Inches		Millimeters		
DIM	MIN	MAX	MIN	MAX	
А	0.031	0.047	0.80	1.20	
С	0.002	0.010	0.05	0.25	
HE	0.138	0.154	3.50	3.90	
E	0.061	0.077	1.55	1.95	
D	0.098	0.114	2.50	2.90	
g	0.020	0.043	0.50	1.10	
е	0.024	0.039	0.60	1.00	
k	0.004		0.	10	
Z	7°				



Unit:mm

### Ordering information

Device	Package	Shipping
PTVSHC1DF18VB	SOD-123FL (Pb-Free)	3000 / Tape & Reel

Suggested PCB Layout

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